

1. Record Nr.	UNISA996390157903316
Autore	Vicars John <1579 or 80-1652.>
Titolo	The opinion of the Roman judges touching imprisonment, and the liberty of the subject, or, A sermon preached at the Abby at Westminster, at a late publique fast, Jan. 25. 1642 [[electronic resource]] / By J.V. Prisoner
Pubbl/distr/stampa	[London, : s.n.], Printed in the yeare of our Lord, 1643
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Formato	Materiale a stampa
Livello bibliografico	Monografia
Note generali	Attributed to John Vicars by Halkett and Laing and Wing. Place of publication from Wing. Annotation on Thomason copy: "Vicars"; "Feb: 6th 1642". Reproduction of the original in the British Library.
Sommario/riassunto	eebo-0018

2. Record Nr.	UNISALENT0991002087199707536
Autore	Limone, Oronzo
Titolo	La tradizione manoscritta della Vita Gregorii magni di Paolo Diacono (B. H.L. 3639) : censimento dei testimoni / Oronzo Limone
Pubbl/distr/stampa	Spoleto : Centro italiano di studi sull'alto medioevo, [1988?]
Descrizione fisica	P. 888-953 ; 23 cm.
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Autore	Lidow Alex
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Altri autori (Persone)	De RooijMichael GlaserJohn (Electrical engineer) PozoAlejandro ZhangShengke PalmaMarco ReuschDavid StrydomJohan
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Soggetti	Field-effect transistors Power transistors Gallium nitride

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Sommario/riassunto	<p>An up-to-date and concise review of GaN transistor design and applications. In the newly revised fourth edition of <i>GaN Power Devices for Efficient Power Conversion</i>, a team of distinguished researchers and practicing engineers deliver a concise and effective new guide to designing small, energy-efficient, and inexpensive products with GaN transistors. This new edition covers all relevant new GaN technology advancements, allowing students and practicing engineers to get, and stay ahead of, the curve with GaN device and circuit technology. You'll explore applications including DC to DC converters, solar inverters, motor drive controllers, satellite electronics, and LiDAR devices. The 4th edition offers critical updates for space applications, vertical GaN, and driving transistors and integrated circuits. New chapters on reliability testing advancements, device wear out mechanisms, thermal management, and the latest developments in monolithic integration round out the book. Readers will also find:</p> <ul style="list-style-type: none"><li>* The latest updates on significant technology improvements, like integrated circuits, reliability studies, and new applications</li><li>* Comprehensive explorations of integrated circuit construction, characteristics, reliability results, and applications</li><li>* Practical discussions of specific circuit designs, layout, and thermal dissipation when designing power conversion systems</li><li>* Chapters written by practicing expert leaders in the power semiconductor field and industry pioneers</li></ul> <p>Perfect for practicing power conversion engineers, <i>GaN Power Devices for Efficient Power Conversion</i> will also benefit electrical engineering students and device scientists in the field of power electronics.</p>